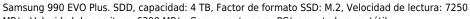
Samsung 990 EVO Plus 4 TB M.2 PCI Express 4.0 NVMe V-NAND TI C

Marca : Samsung Código del producto: MZ-V9S4T0B/AM

Nombre del producto: 990 EVO Plus



MB/s, Velocidad de escritura: 6300 MB/s, Componente para: PC/computadora portátil





Features		Power	
NVMe version Security algorithms SSD capacity * SSD form factor * Interface * NVMe * Memory type * Component for * M.2 SSD size Read speed Write speed Random read (4KB) Random write (4KB) S.M.A.R.T. support Mean time between failures (MTBF) TBW rating 256-bit AES 2750-bit AES 2750-bit AES 4 TB M.2 SSD size PCI Express 4.0 NVMe * ✓ V-NAND TLC PC/Laptop 4 V-NAND TLC 2280 (22 x 80 mm) 7250 MB/s 1050000 IOPS 1400000 IOPS 1400000 IOPS 1500000 h 1500000 h 1500000 h 1500000 h	256-bit AES 4 TB	Power consumption (read) Power consumption (write) Power consumption (idle)	5.5 W 4.8 W 0.06 W
	PCI Express 4.0 ✓ V-NAND TLC	Weight & dimensions Width Depth Height	80.2 mm 22.1 mm 2.38 mm
	✓ 2280 (22 x 80 mm)	Packaging data Package type Operational conditions	Hanging box
	6300 MB/s 1050000 IOPS 1400000 IOPS	Operating temperature (T-T) Storage temperature (T-T) Operating relative humidity (H-H) Storage relative humidity (H-H) Non-operating shock	0 - 70 °C -40 - 85 °C 5 - 95% 5 - 95% 1500 G
		Vibration resistance Other features	20 G
		Warranty period Compliance certificates	5 year(s) KCC, Federal Communications Commission (FCC), CE

